

Technical Data Sheet

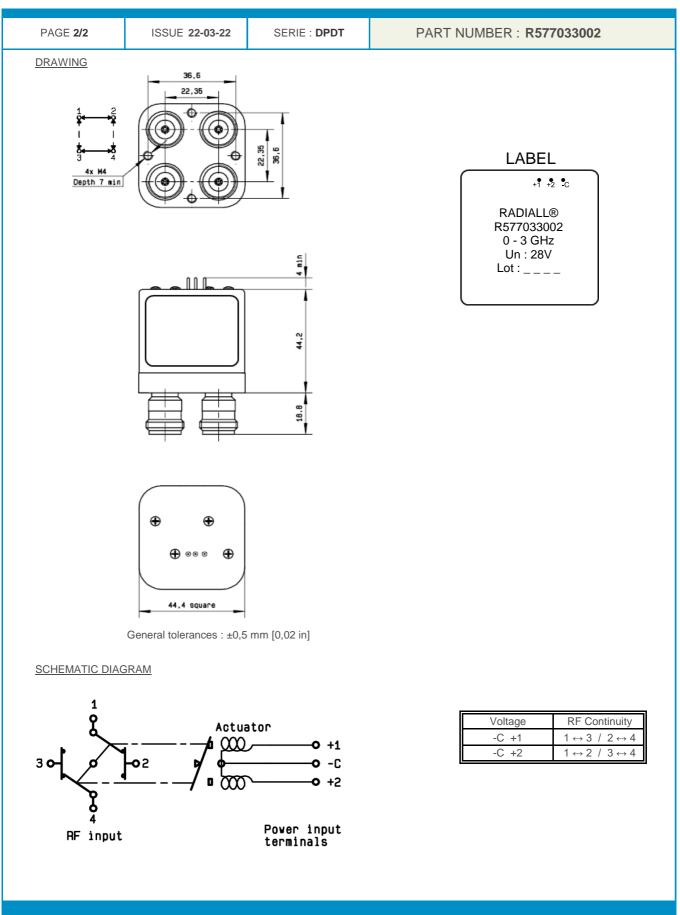
DPDT Ramses N 3GHz Latching 28Vdc Pins Terminals

	HARACTERI							
	Frequency r Impedance	ange			0 - 3 GHz 50 Ohms			
	Frequency (GHz)	DC - 1	1 - 2	2 - 3			
	VSWR max		1.15	1.20	1.25			
	Insertion los		0.15 dB	0.20 dB	0.25 dB			
	Isolation min		85 dB 700 W	80 dB 500 W	75 dB 400 W			
<u>ELE(</u>	Actuator Nominal cur Actuator vol Terminals	rent **	<u>FICS</u>	:	-	0V) / NEGATIVE C((250°C max. / 30 se		
MEC	HANICAL CH	ARACTERIS	<u>STICS</u>					
	Connectors			:	N female pe	r MIL-C 39012		
	Life				2.5 million o	cycles		
	Switching Ti Construction				< 15 ms Splashproo	f		
	Weight	1			< 215 g	•		
ENV	IRONMENTA	_ CHARACT	ERISTICS					
	Operating te	mperature ra	ange	:	-40°C to +85	5°C		
		perature ran	-	:	-55°C to +85	5°C	R	oHS
(* (** (***	At 25° C ±10	ver at 25°C p 0%) :age ; 25° C)	er RF Path)				· COM	PLIAN



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